

SHINDENGEN

General Purpose Rectifiers

SIL Bridges

S1VB80

800V 1A

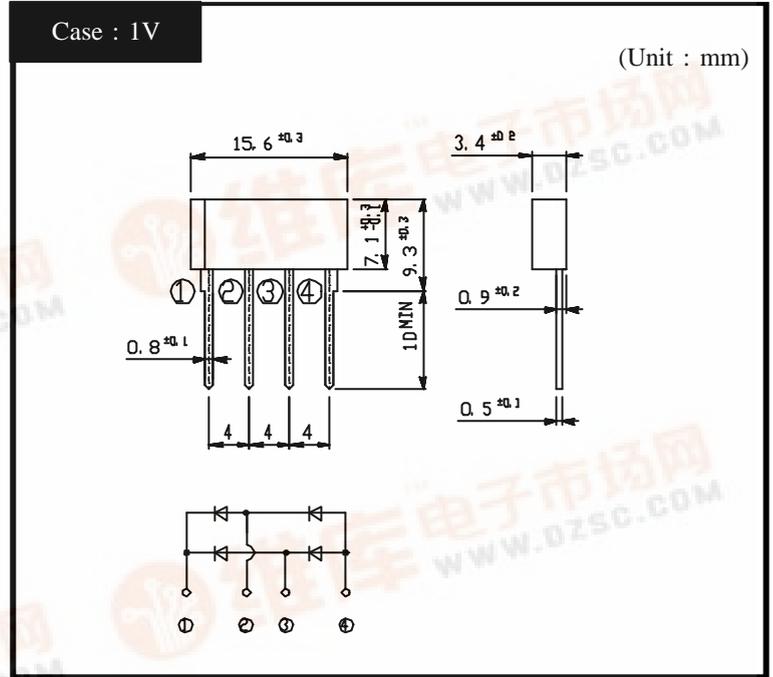
FEATURES

- Small Single In-Line (:SIL)Package
- High IFSM
- Applicable to Automatic Insertion

APPLICATION

- Switching power supply
- Home Appliance, Office Equipment
- Telecommunication, Factory automation

OUTLINE DIMENSIONS



RATINGS

Absolute Maximum Ratings (If not specified Tl=25)

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T _{stg}		-40 ~ 150	
Operating Junction Temperature	T _j		150	
Maximum Reverse Voltage	V _{RM}		800	V
Average Rectified Forward Current	I _O	50Hz sine wave, R-load, On glass-epoxy substrate Ta=25	1	A
Peak Surge Forward Current	I _{FSM}	50Hz sine wave, Non-repetitive 1cycle peak value, Tj=25	30	A
Current Squared Time	I ² t	1ms t < 10ms Tj=25	4.5	A ² s

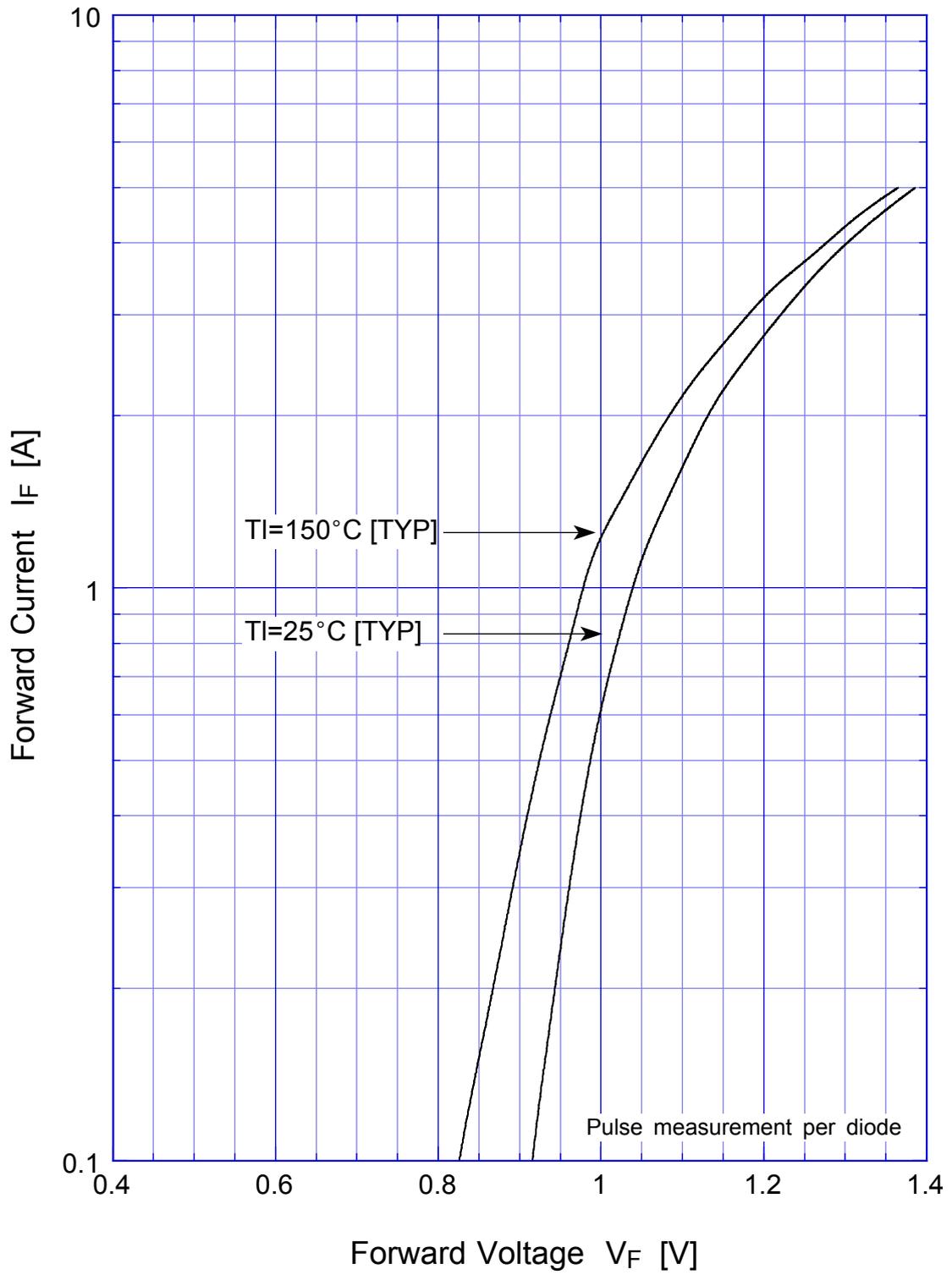
Electrical Characteristics (If not specified Tl=25)

Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V _F	I _F =0.5A, Pulse measurement, Rating of per diode	Max.1.05	V
Reverse Current	I _R	V _R =V _{RM} , Pulse measurement, Rating of per diode	Max.10	μA
Thermal Resistance	j-l	junction to lead	Max.16	/W
	ja	junction to ambient	Max.62	



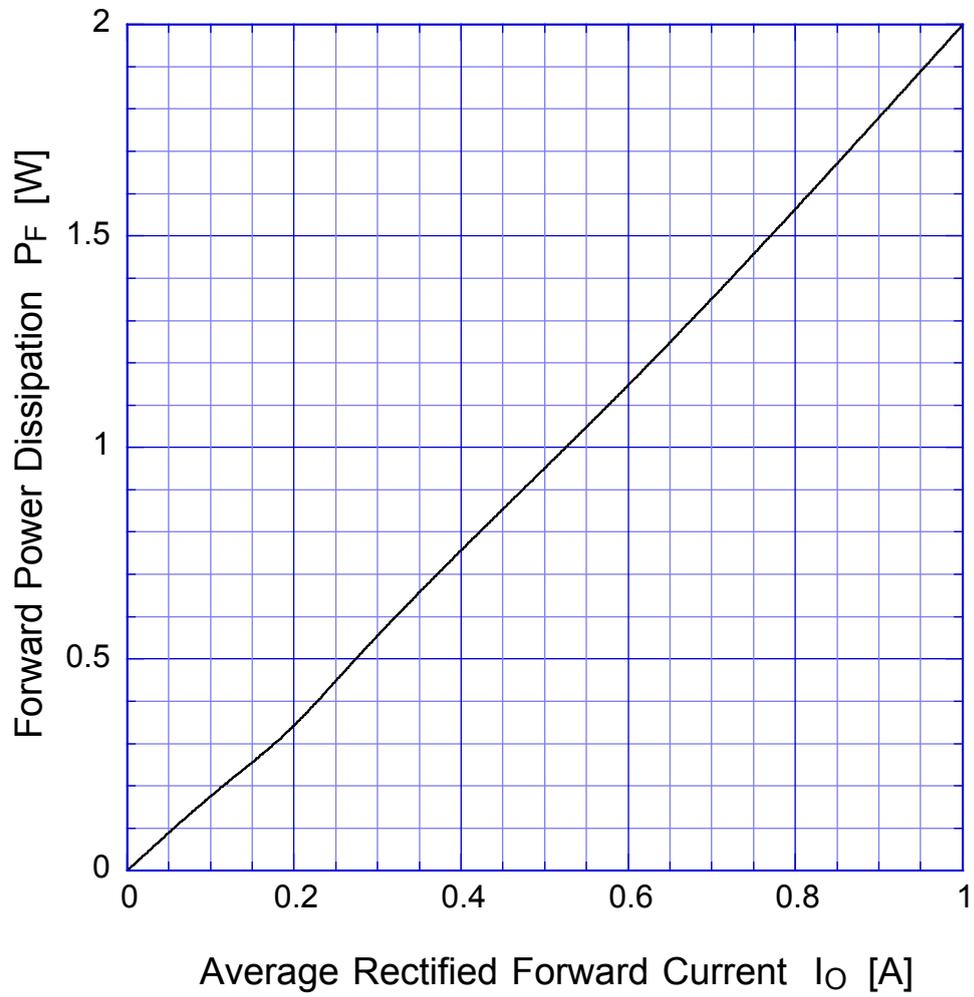
S1VBx

Forward Voltage



S1VBx

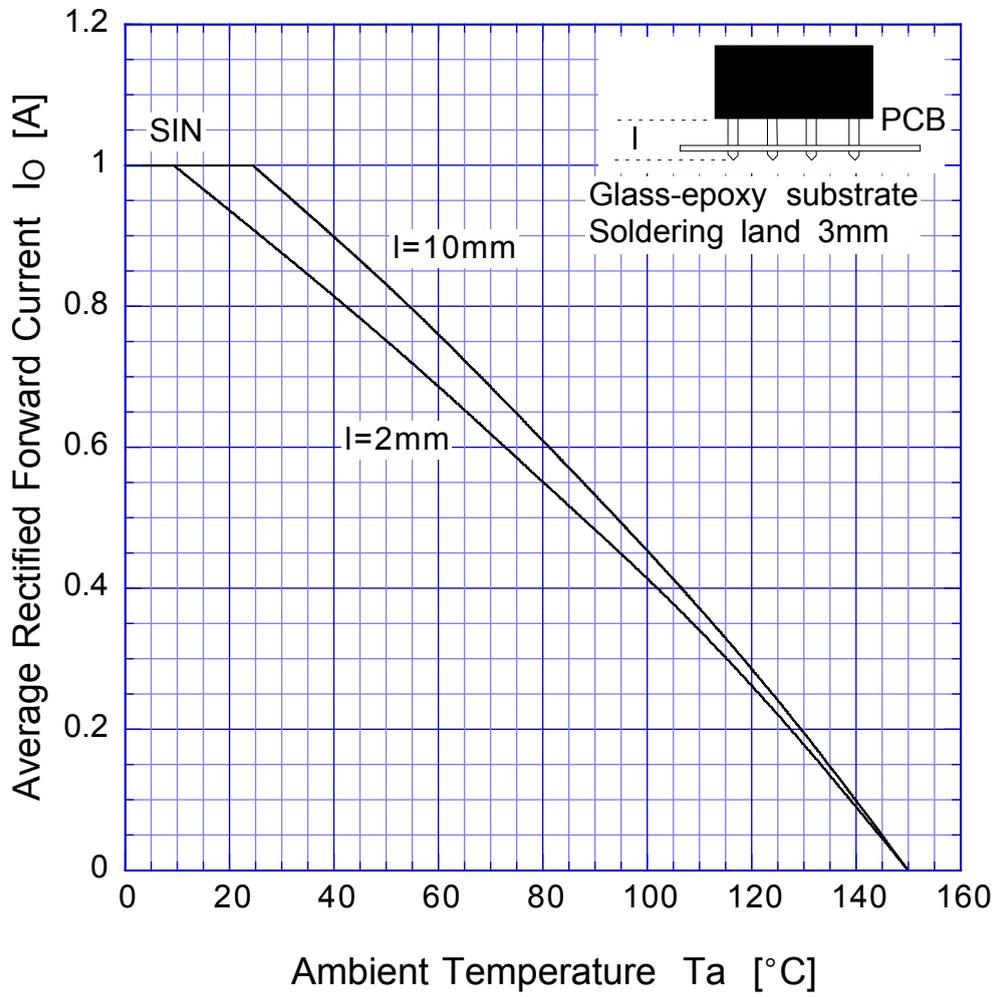
Forward Power Dissipation



$T_j = 150^\circ\text{C}$
Sine wave

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Derating Curve



Sine wave
R-load
Free in air

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Peak Surge Forward Capability

